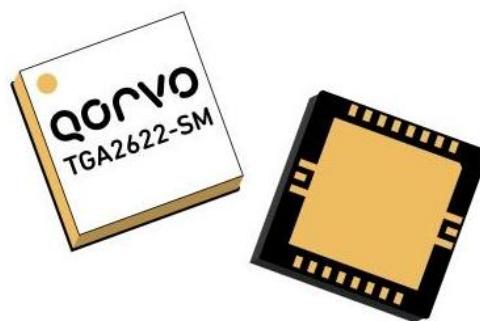
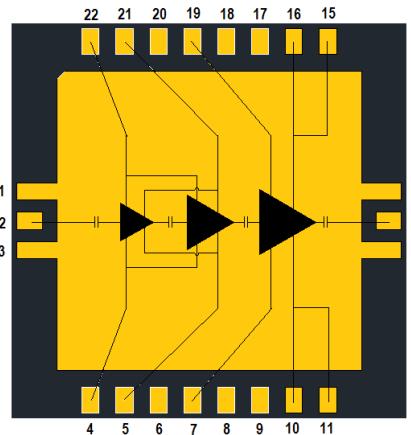


Product Description

Qorvo's TGA2622-SM is a packaged, high power X-Band amplifier fabricated on Qorvo's production 0.25um GaN on SiC process. Operating from 9-10GHz, the TGA2622-SM typically generates 35W of saturated output power with a power-added efficiency greater than 42% and 27.5dB of large signal gain.

The TGA2622-SM is packaged in a 7x7mm air-cavity, laminate based QFN. Both RF ports are internally DC blocked and matched to 50 ohms enabling simple system integration. Ideally suited for pulsed applications, the TGA2622-SM offers superior power, PAE and gain performance that can save costs on existing platforms while enabling the development of future systems.

Functional Block Diagram



QFN 7x7 mm 22L

Product Features

- Frequency Range: 9 – 10 GHz
- P_{SAT} : 45.5 dBm @ $P_{IN} = 18$ dBm
- PAE: 42% @ $P_{IN} = 18$ dBm
- Power Gain: 27.5 dB @ $P_{IN} = 18$ dBm
- Bias: $V_D = 28$ V, $I_{DQ} = 290$ mA
(Pulsed V_D : $P_W = 100$ us and DC = 10 %)
- Package Dimensions: 7 x 7 x 1.64 mm

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

Ordering Information

| Part | Description |
|----------------|-------------------------------------|
| TGA2622-SM | 9 – 10 GHz 35 W GaN Power Amplifier |
| TGA2622-SM EVB | Evaluation Board |

Applications

- Weather and Marine Radar

Absolute Maximum Ratings

| Parameter | Value |
|--|---------------|
| Drain Voltage (V_D) | 40 V |
| Gate Voltage Range (V_G) | -8 to 0V |
| Drain Current (I_D) | 4.3 A |
| Gate Current (I_G) | See page 11 |
| Power Dissipation (P_{DISS}), 85°C, CW | 88 W |
| Input Power (P_{IN}), CW, 50Ω, $V_D = 28V$, 85°C | 24 dBm |
| Input Power (P_{IN}), CW, VSWR 3:1, $V_D = 28V$, 85°C | 24 dBm |
| Mounting Temperature (30 seconds) | 260 °C |
| Storage Temperature | -55 to 150 °C |

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

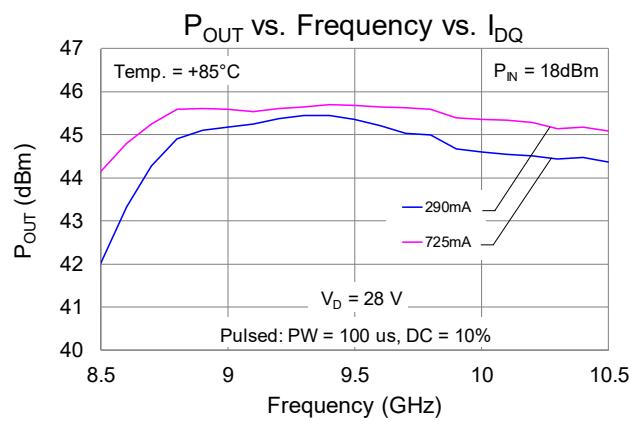
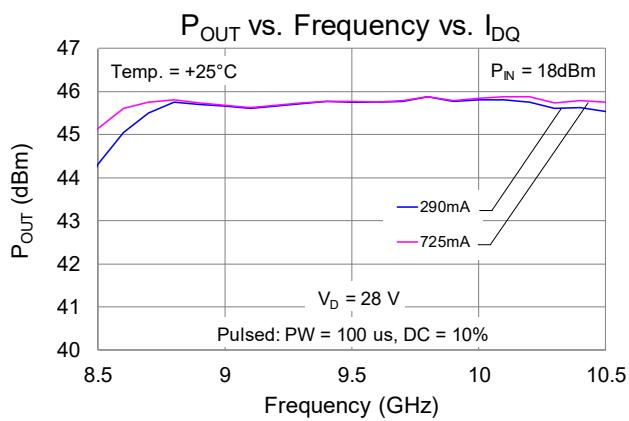
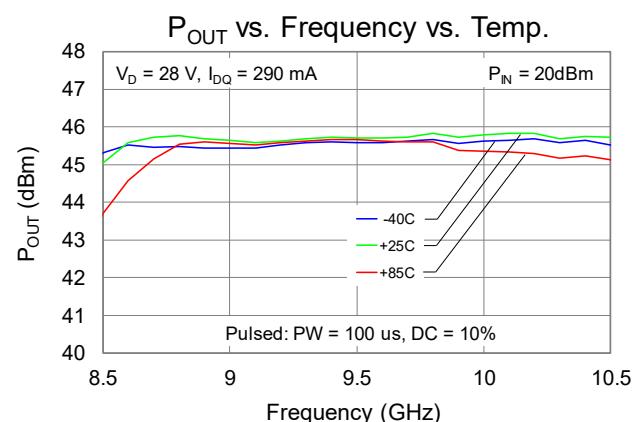
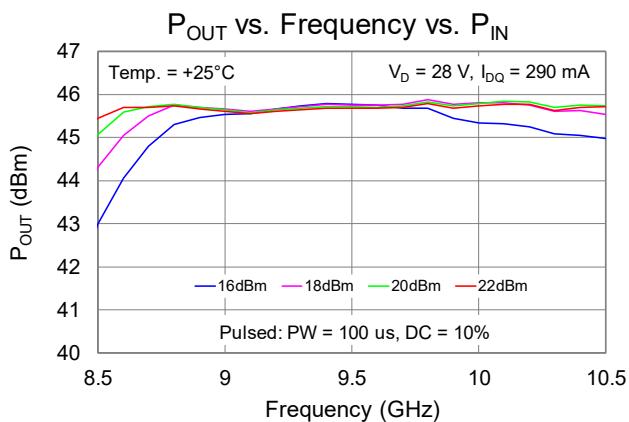
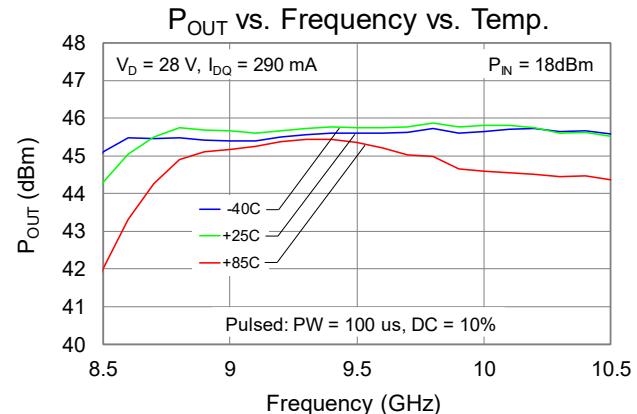
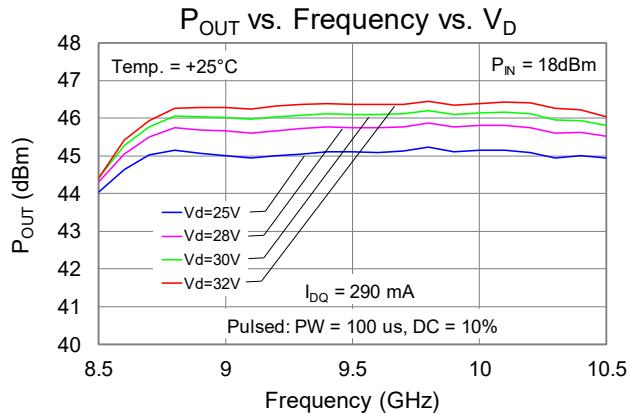
| Parameter | Value |
|---|----------------|
| Drain Voltage (V_D) | 28 V |
| Drain Current (quiescent, I_{DQ}) | 290 mA |
| Gate Voltage Range (V_G) | -2.8 to -2.0 V |
| Operating Temperature Range | -40 to 85 °C |
| Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions. | |

Electrical Specifications

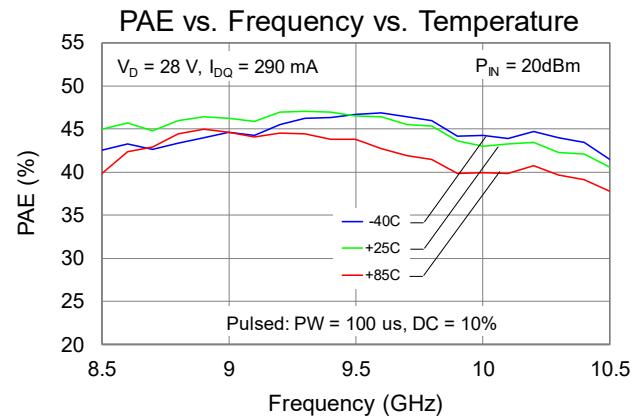
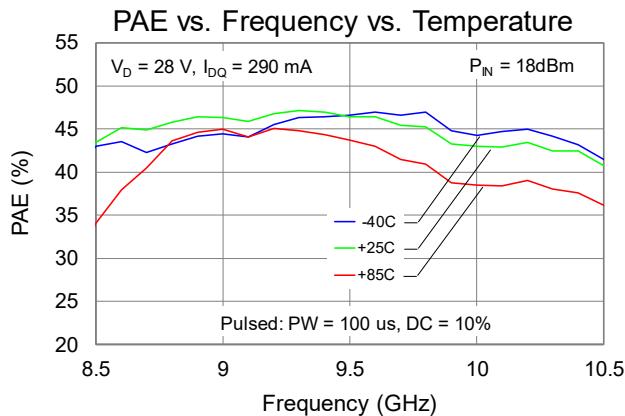
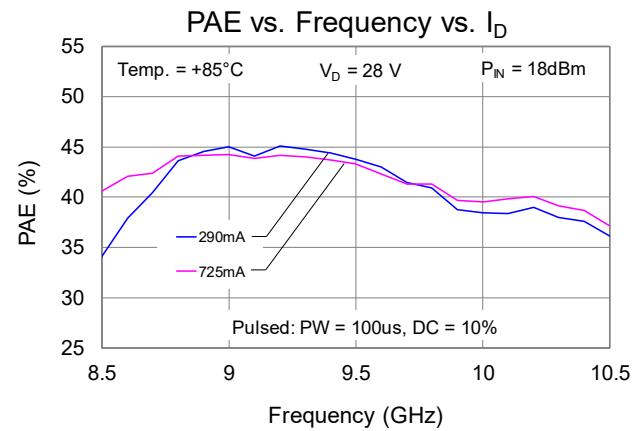
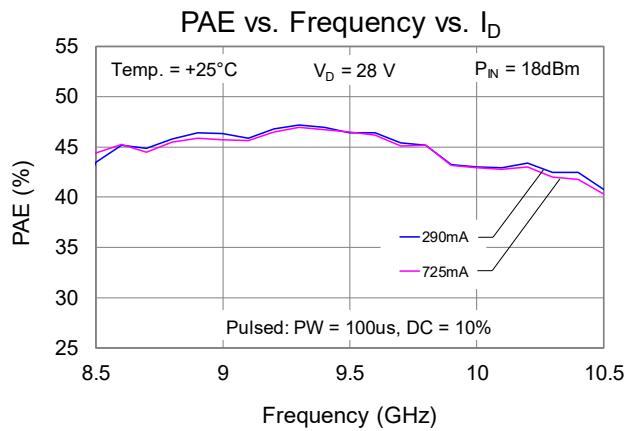
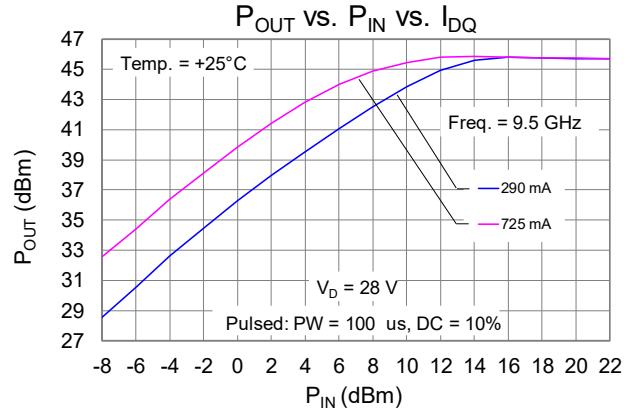
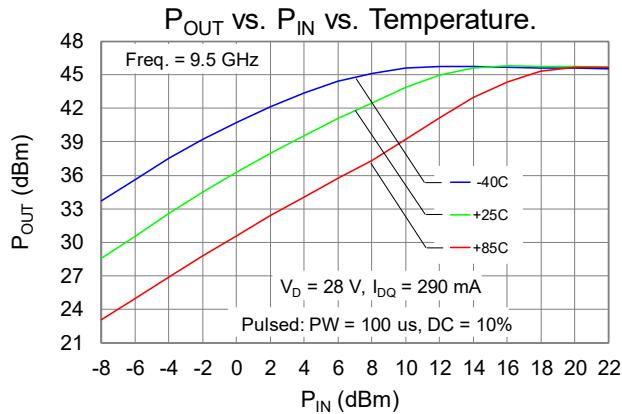
Test conditions unless otherwise noted: 25 °C, $V_D = 28$ V, $I_{DQ} = 290$ mA, Pulsed V_D : PW = 100 us, DC = 10%

| Parameter | | Min | Typ | Max | Units |
|--|---------------------|-----|-------|-----|--------|
| Operational Frequency Range | | 9 | – | 10 | GHz |
| Output Power @ $P_{IN} = 18$ dBm | Frequency = 9 GHz | 45 | 45.7 | – | dBm |
| | Frequency = 9.5 GHz | 45 | 45.8 | – | dBm |
| | Frequency = 10 GHz | 45 | 45.8 | – | dBm |
| Power Added Efficiency @ $P_{IN} = 18$ dBm | Frequency = 9 GHz | 40 | 46.4 | – | % |
| | Frequency = 9.5 GHz | 40 | 46.4 | – | % |
| | Frequency = 10 GHz | 35 | 43 | – | % |
| Small Signal Gain | Frequency = 9 GHz | – | 31.5 | – | |
| | Frequency = 9.5 GHz | – | 32.7 | – | |
| | Frequency = 10 GHz | – | 31.4 | – | |
| Input Return Loss | Frequency = 9 GHz | – | 14.7 | – | |
| | Frequency = 9.5 GHz | – | 15 | – | |
| | Frequency = 10 GHz | – | 11 | – | |
| Output Return Loss | Frequency = 9 GHz | – | 10.6 | – | |
| | Frequency = 9.5 GHz | – | 9.3 | – | |
| | Frequency = 10 GHz | – | 12 | – | |
| Output Power Temperature Coefficient From 25°C to 85°C (Pin = 18dBm) | | – | -0.02 | – | dBm/°C |

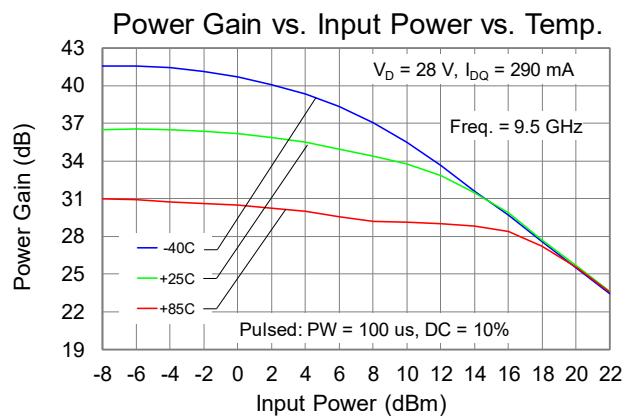
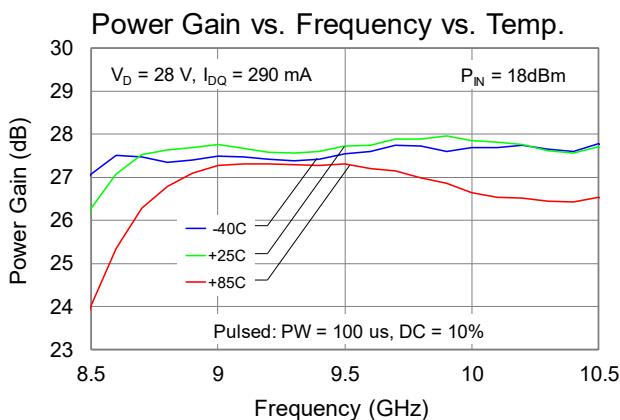
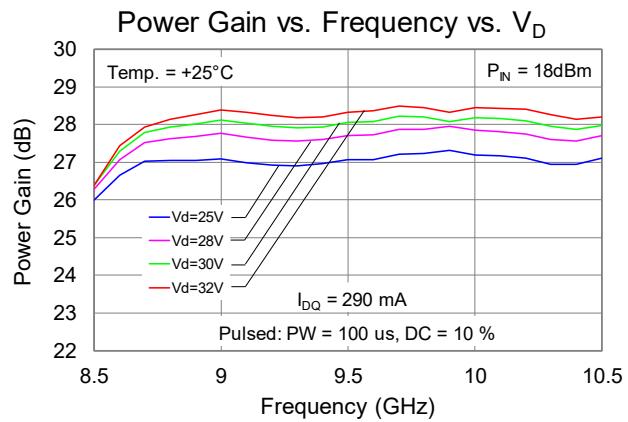
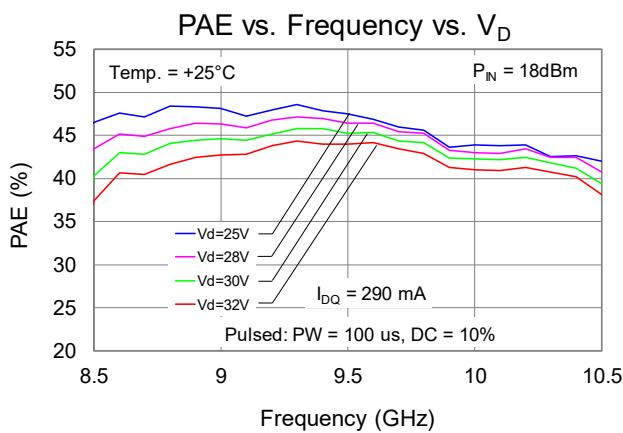
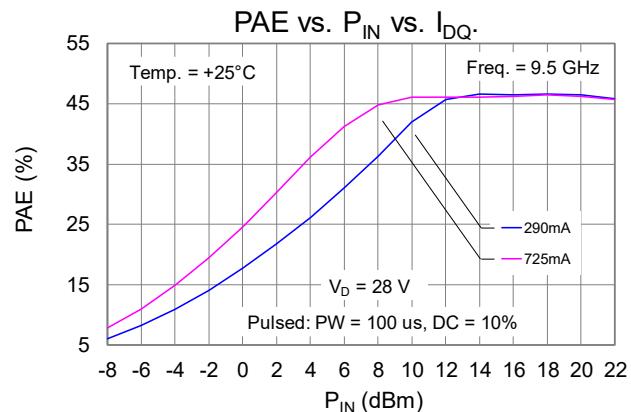
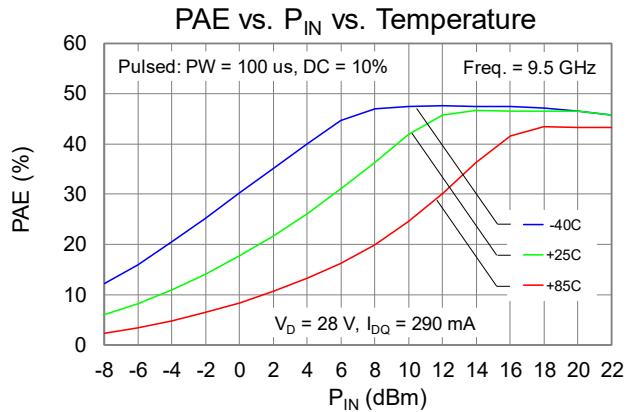
Performance Plots – Large Signal (Pulsed)



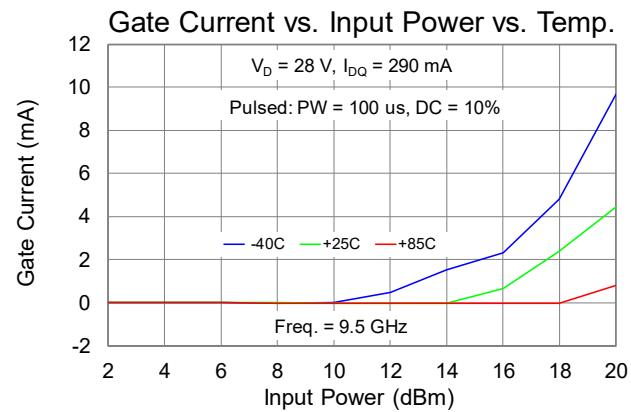
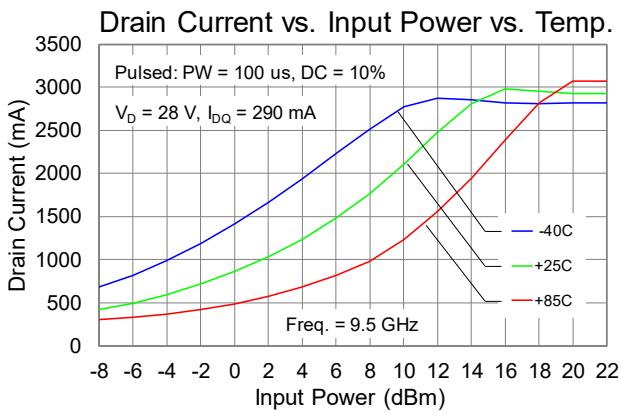
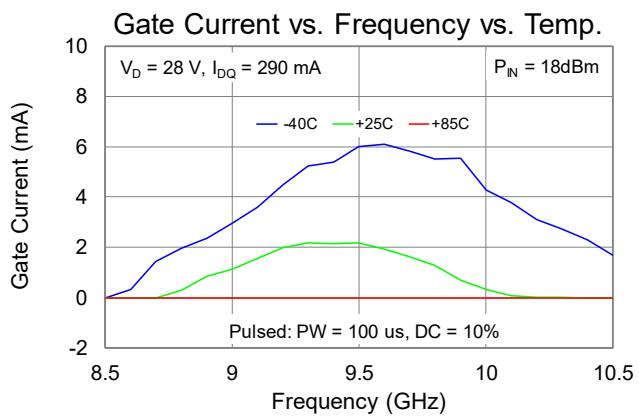
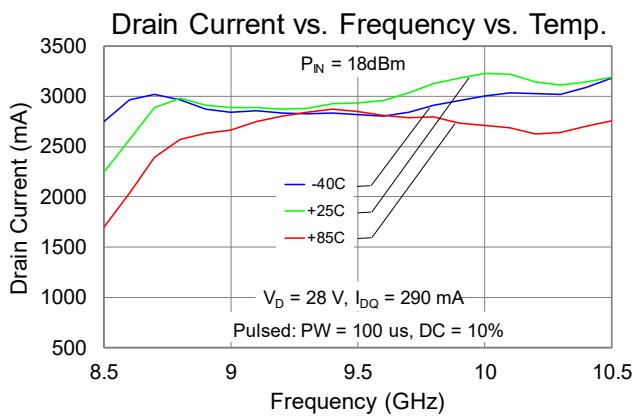
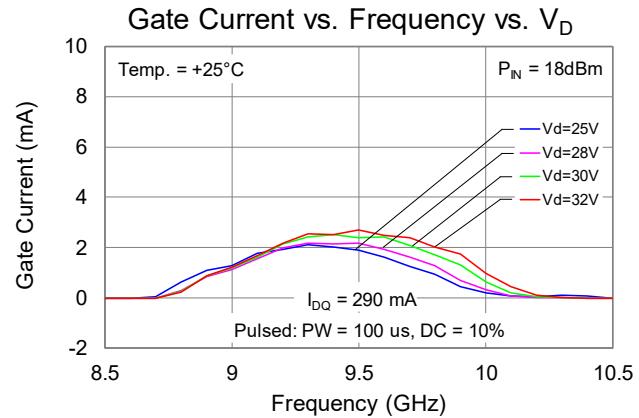
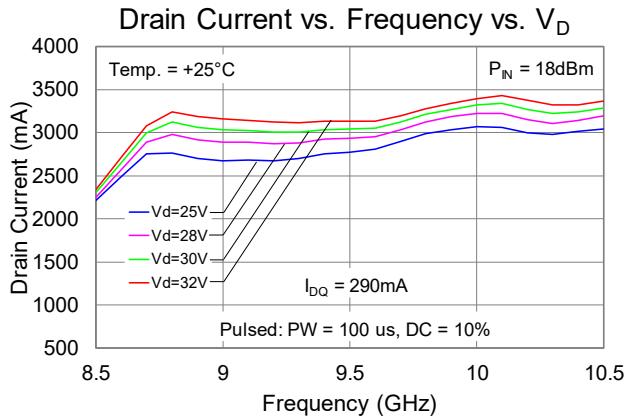
Performance Plots – Large Signal (Pulsed)



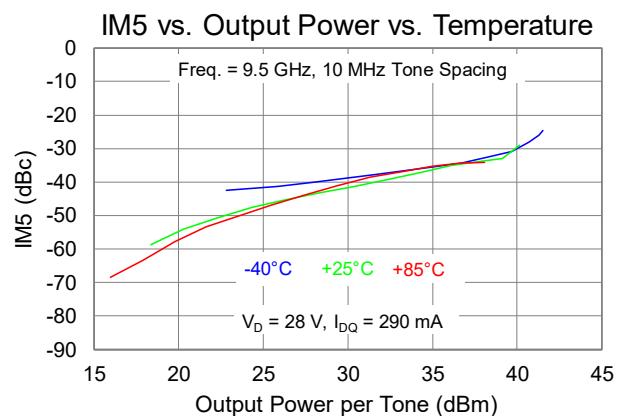
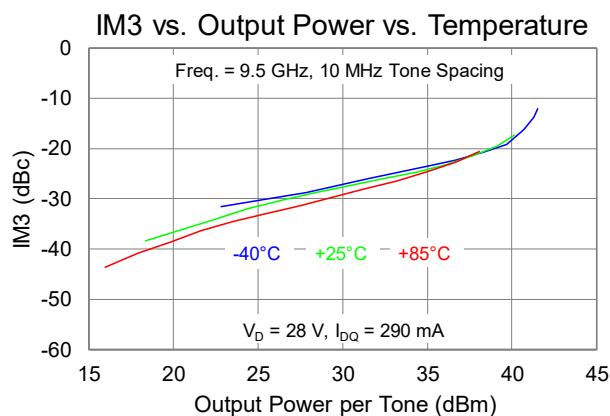
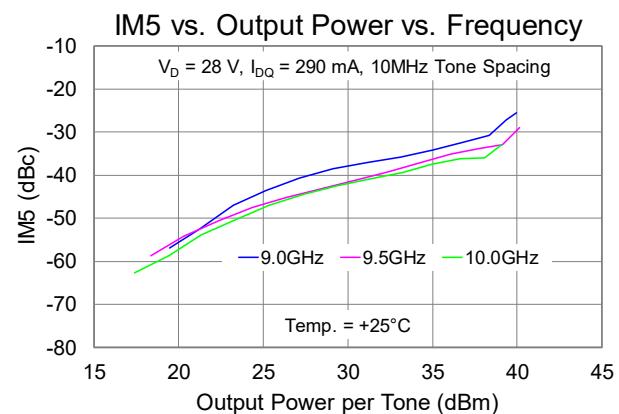
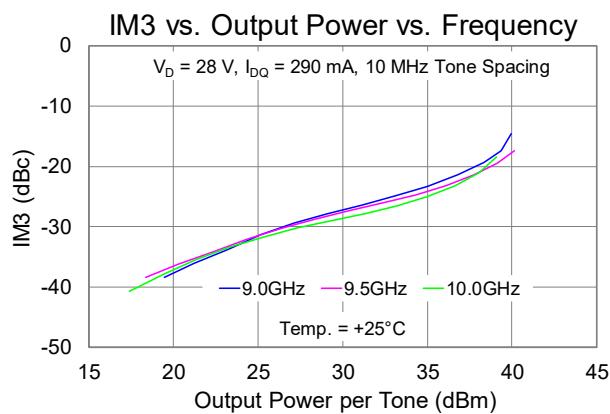
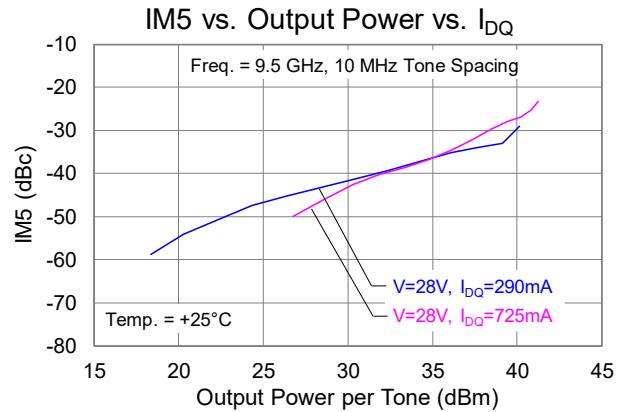
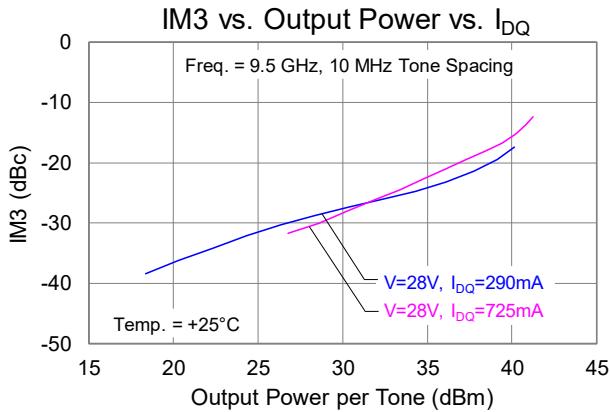
Performance Plots – Large Signal (Pulsed)



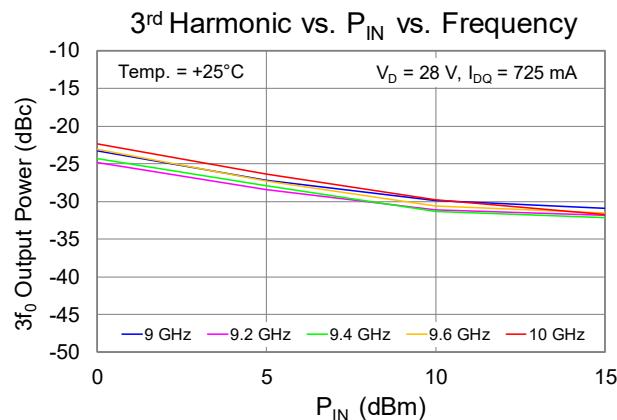
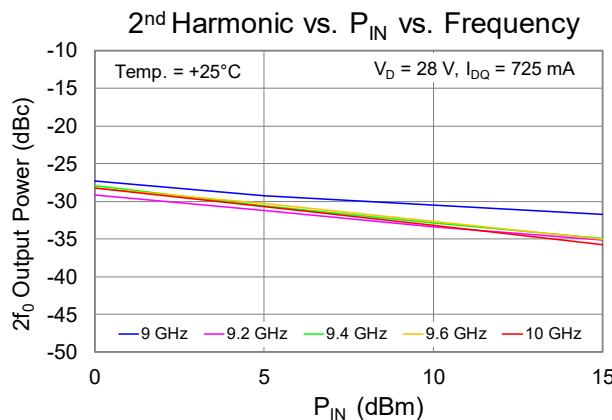
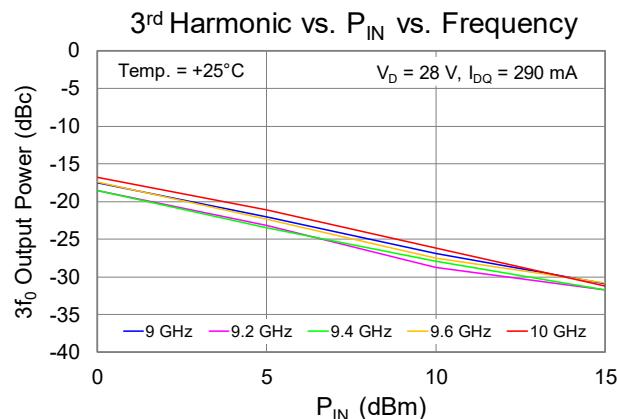
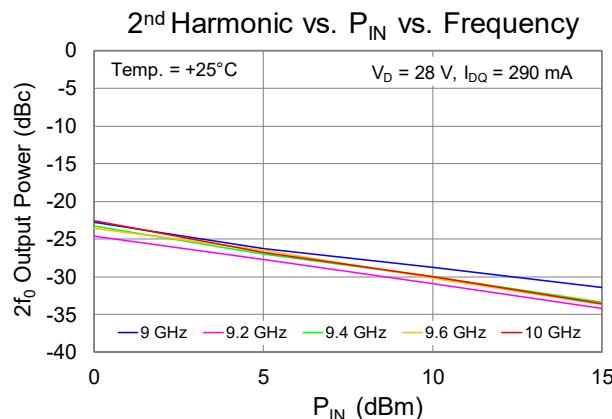
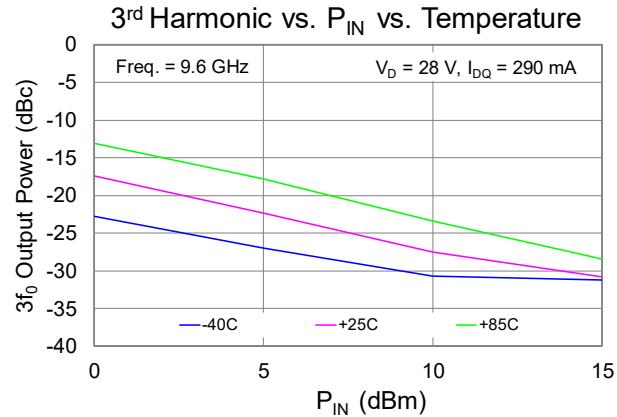
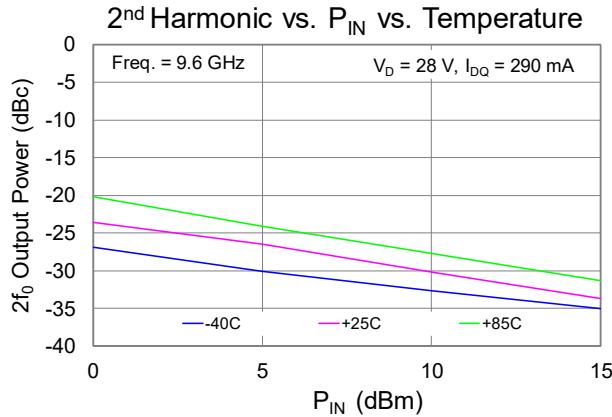
Performance Plots – Large Signal (Pulsed)



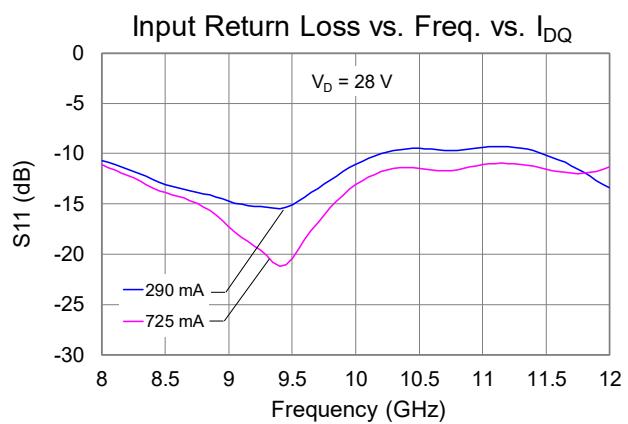
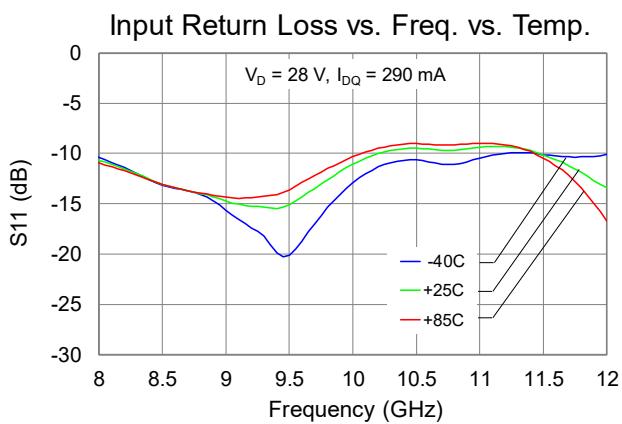
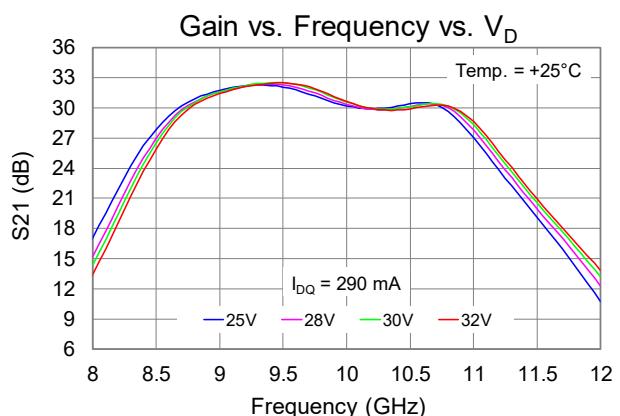
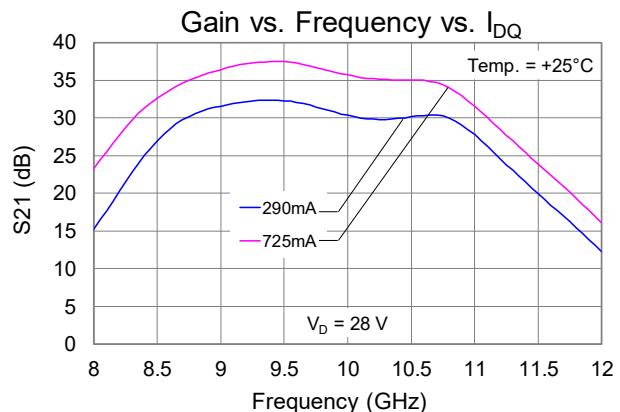
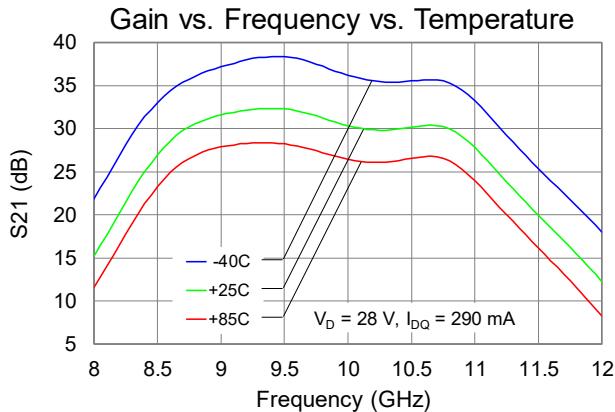
Performance Plots – Linearity (CW)



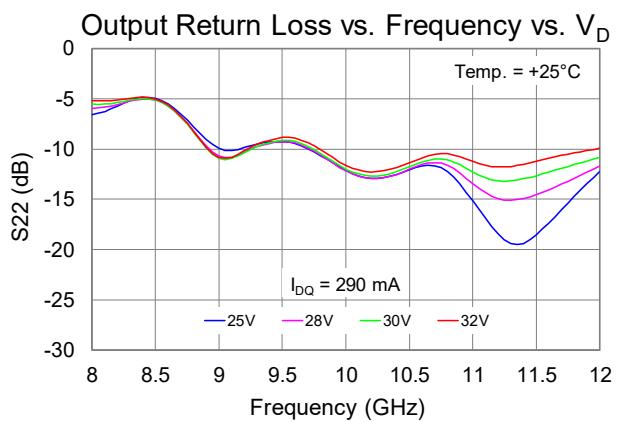
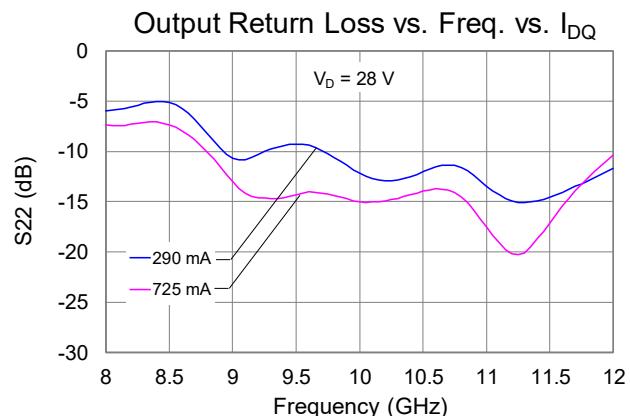
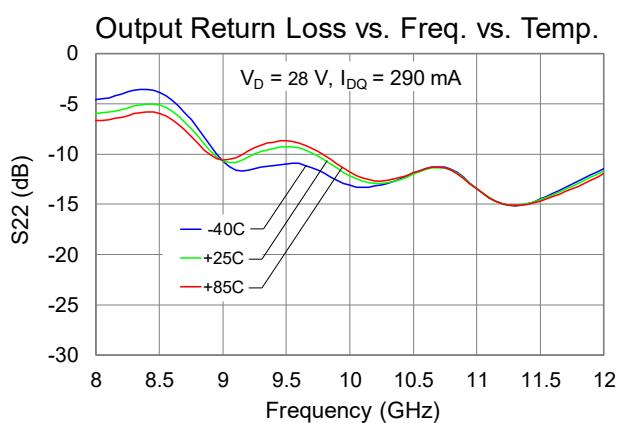
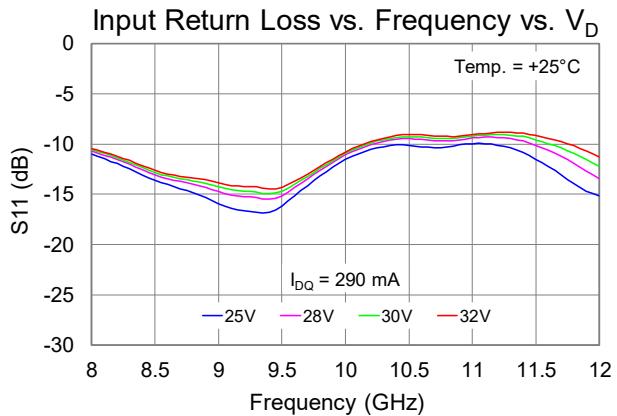
Performance Plots – Linearity (CW)



Performance Plots – Small Signal (CW)



Performance Plots – Small Signal (CW)



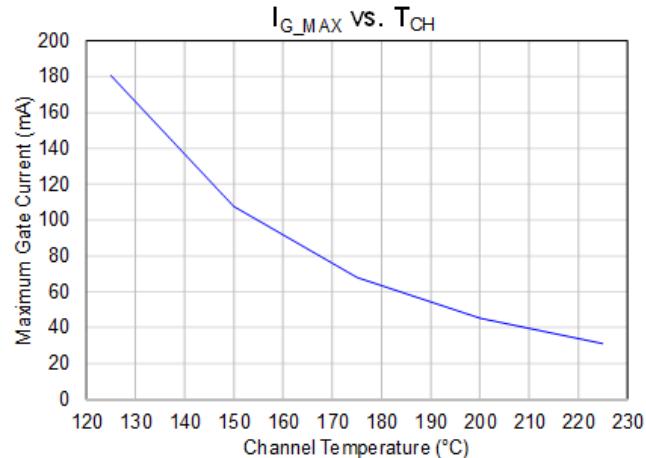
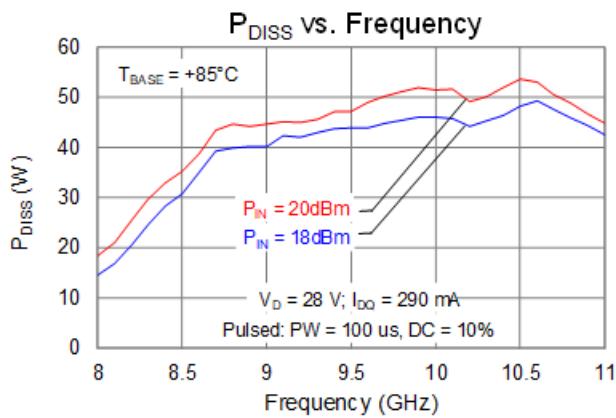
Thermal and Reliability Information

| Parameter | Test Conditions | Value | Units |
|---|---|-------|-------|
| Thermal Resistance (θ_{JC}) ⁽¹⁾ | $T_{base} = 85^\circ\text{C}$, $V_D = 28\text{ V}$, $I_{DQ} = 290\text{ mA}$, Small signal or quiescent. $P_{DISS} = 8.12\text{ W}$ | 0.51 | °C/W |
| Channel Temperature (T_{CH}) (Small Signal) ² | | 89.1 | °C |
| Thermal Resistance (θ_{JC}) ⁽¹⁾ | $T_{base} = 85^\circ\text{C}$, $V_D = 28\text{ V}$, $I_{DQ} = 290\text{ mA}$, Pulsed V_D , $PW = 100\text{ us}$, $DC = 10\%$, $I_{D_Drive} = 3.1\text{ A}$, $P_{IN} = 20\text{ dBm}$, $P_{OUT} = 45.4\text{ dBm}$, $P_{DISS} = 52\text{ W}$ | 0.73 | °C/W |
| Channel Temperature (T_{CH}) (With RF drive) ² | | 123.2 | °C |
| Thermal Resistance (θ_{JC}) ⁽¹⁾ | $T_{base} = 85^\circ\text{C}$, $V_D = 28\text{ V}$, $I_{DQ} = 290\text{ mA}$, CW, $I_{D_Drive} = 3.1\text{ A}$, $P_{IN} = 20\text{ dBm}$, $P_{OUT} = 45.4\text{ dBm}$, $P_{DISS} = 52\text{ W}$ | 1.19 | °C/W |
| Channel Temperature (T_{CH}) (With RF drive) ² | | 146.9 | °C |

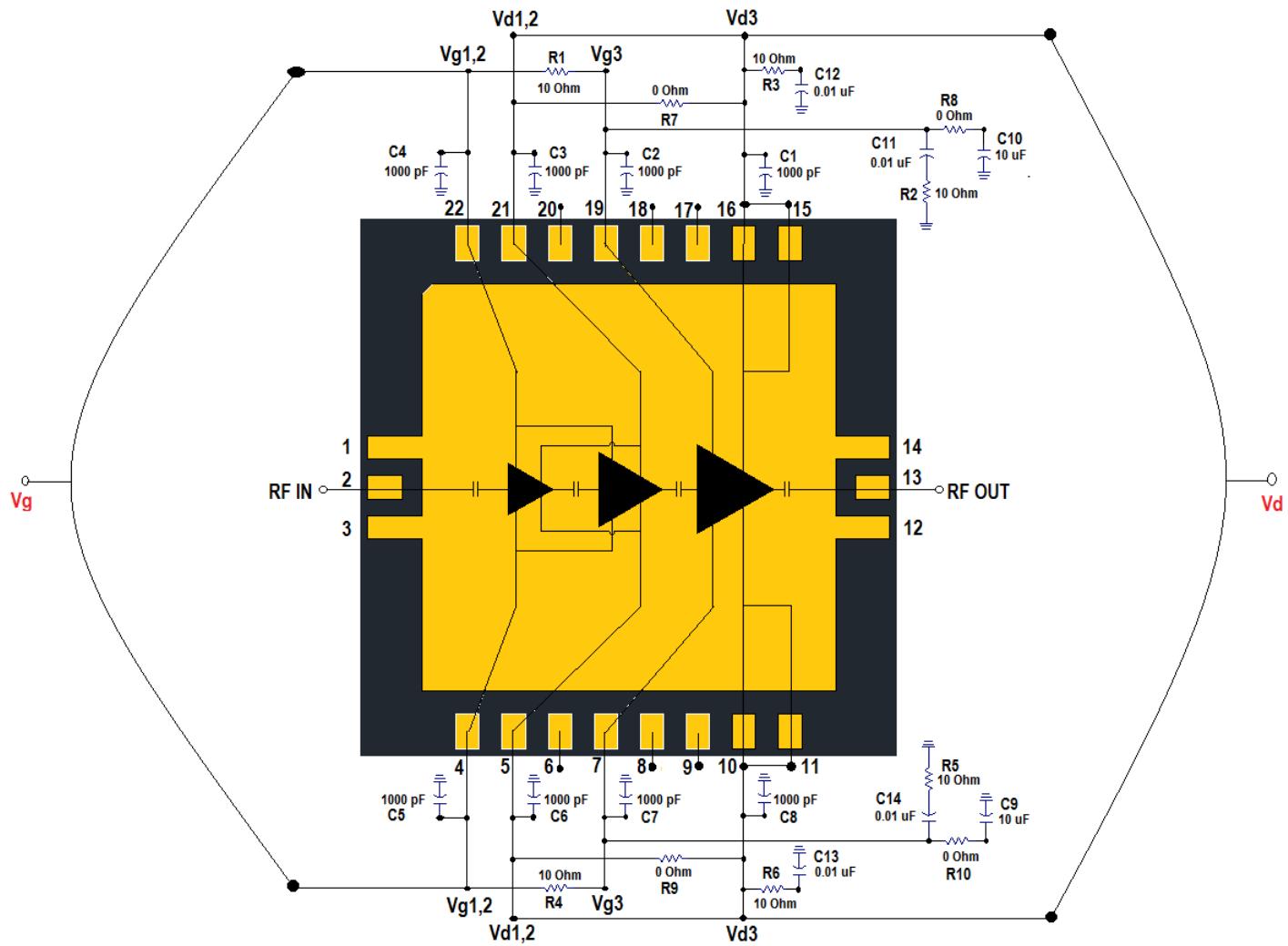
Notes:

1. Thermal Resistance referenced to the back of the package.
2. IR scan equivalent. Refer to the following document: [GaN Device Channel Temperature, Thermal Resistance, and Reliability Estimates](#)

Power Dissipation and Maximum Gate Current



Applications Circuit



Notes:

1. V_G must be biased from both sides - $V_{G1,2}$ & V_{G3} can be tied together.
2. V_D : must be biased from both sides - $V_{D1,2}$ & V_{D3} can be tied together.

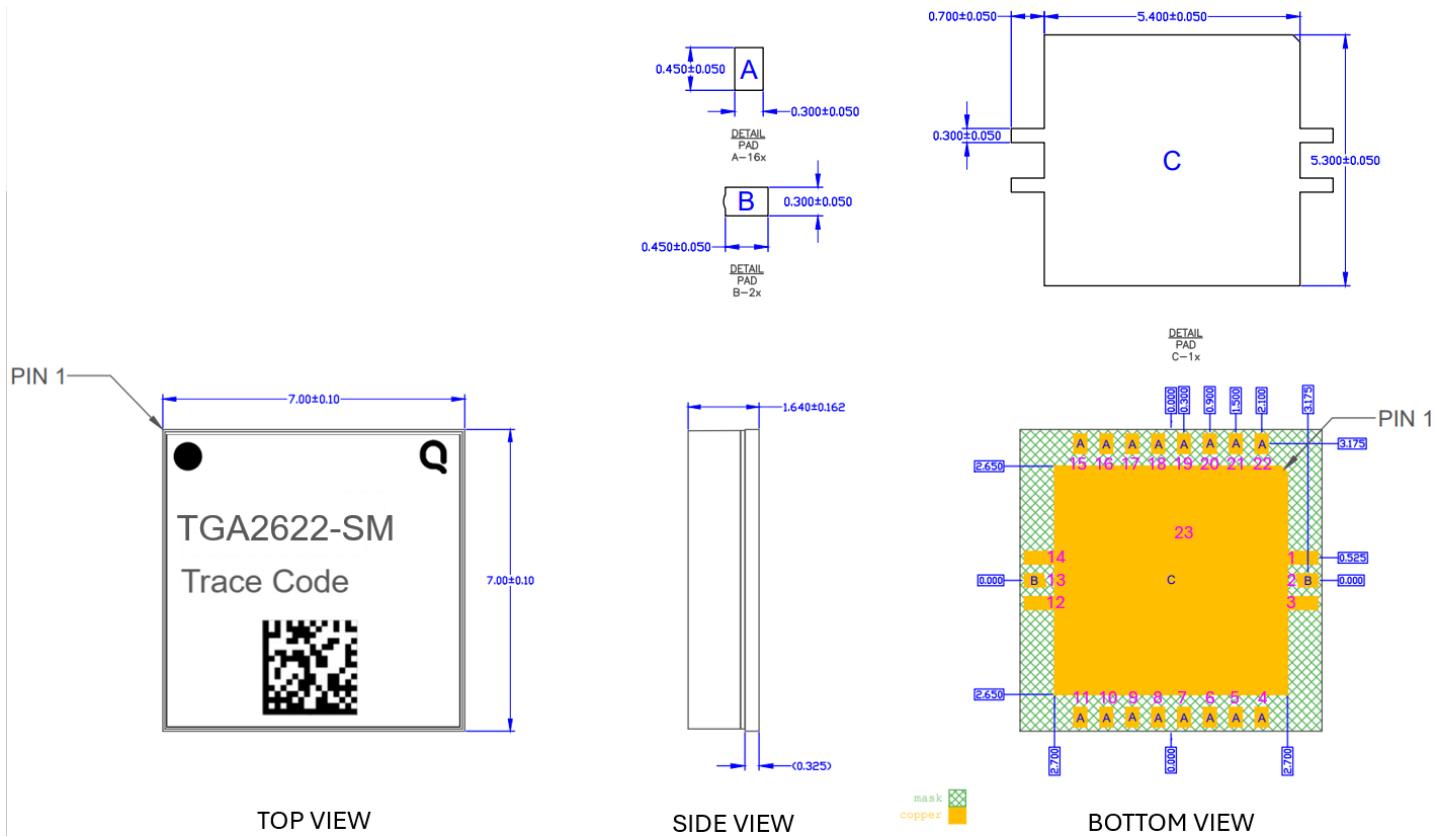
Bias Up Procedure

1. Set I_D limit to 3.5 A, I_G limit to 25 mA
2. Set V_G to -5.0 V (for pinch-off)
3. Set V_D +28 V; Ensure I_{DQ} is approx. 0 mA
4. Adjust V_G more positive until $I_{DQ} = 290$ mA ($V_G \sim -2.3$ V Typical)
5. Apply RF signal

Bias Down Procedure

1. Turn off RF supply
2. Reduce V_G to -5.0V. Ensure $I_{DQ} \sim 0$ mA
3. Set V_D to 0 V
4. Turn off V_D supply
5. Turn off V_G supply

Mechanical Drawing and Pin Layout



Units: Millimeters (mm)
 Tolerances: unless specified: x.xx = ± 0.25 ; x.xxxx = ± 0.100

Materials: Base: Laminate Substrate

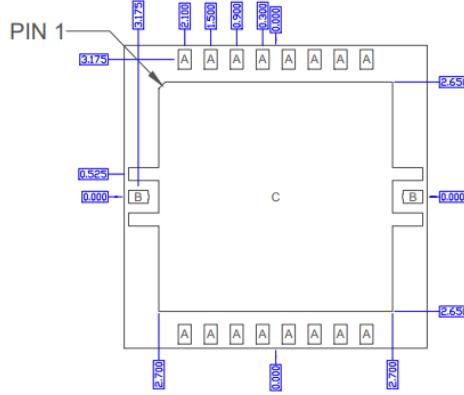
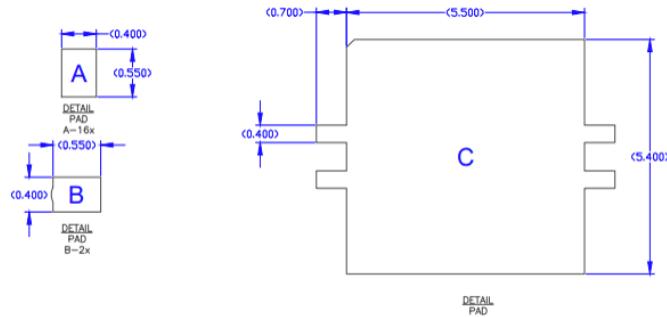
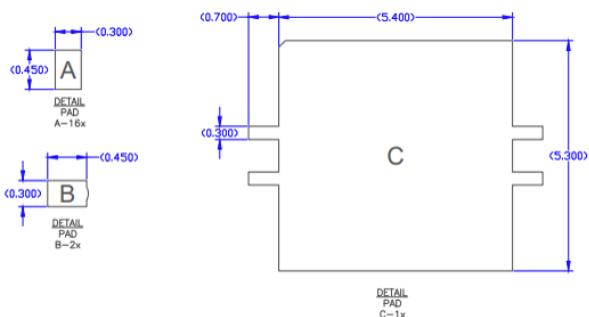
Lid: Laminate

All metallized features are gold plated. Part is epoxy sealed
 2DID Marking can be used to trace part manufacturing information

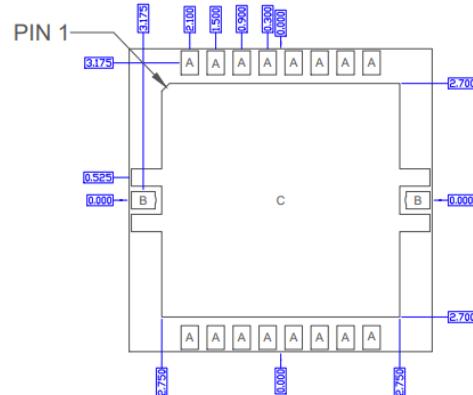
Pin Description

| Pin No. | Symbol | Description |
|---------------------|-------------------|---|
| 1, 3, 12, 14, 23 | GND | Must be grounded on the PCB |
| 2 | RF _{IN} | Input; matched to 50 Ω; DC blocked |
| 4, 22 | V _{G1,2} | Gate Voltages 1,2; Bias network is required; must be biased from both sides; see recommended Application Information on page 12. |
| 5, 21 | V _{D1,2} | Drain voltages 1,2; Bias network is required; must be biased from both sides; see recommended Application Information on page 12. |
| 6, 8, 9, 17, 18, 20 | N/C | No internal connection |
| 7, 19 | V _{G3} | Gate Voltage 3; Bias network is required; must be biased from both sides; see recommended Application Information on page 12. |
| 10, 11, 15, 16 | V _{D3} | Drain voltage 3; Bias network is required; must be biased from both sides; see recommended Application Information on page 12. |
| 13 | RF _{OUT} | Output; matched to 50 Ω; DC blocked |

Application PCB Land Patterns and Masks



Recommended Land Pattern

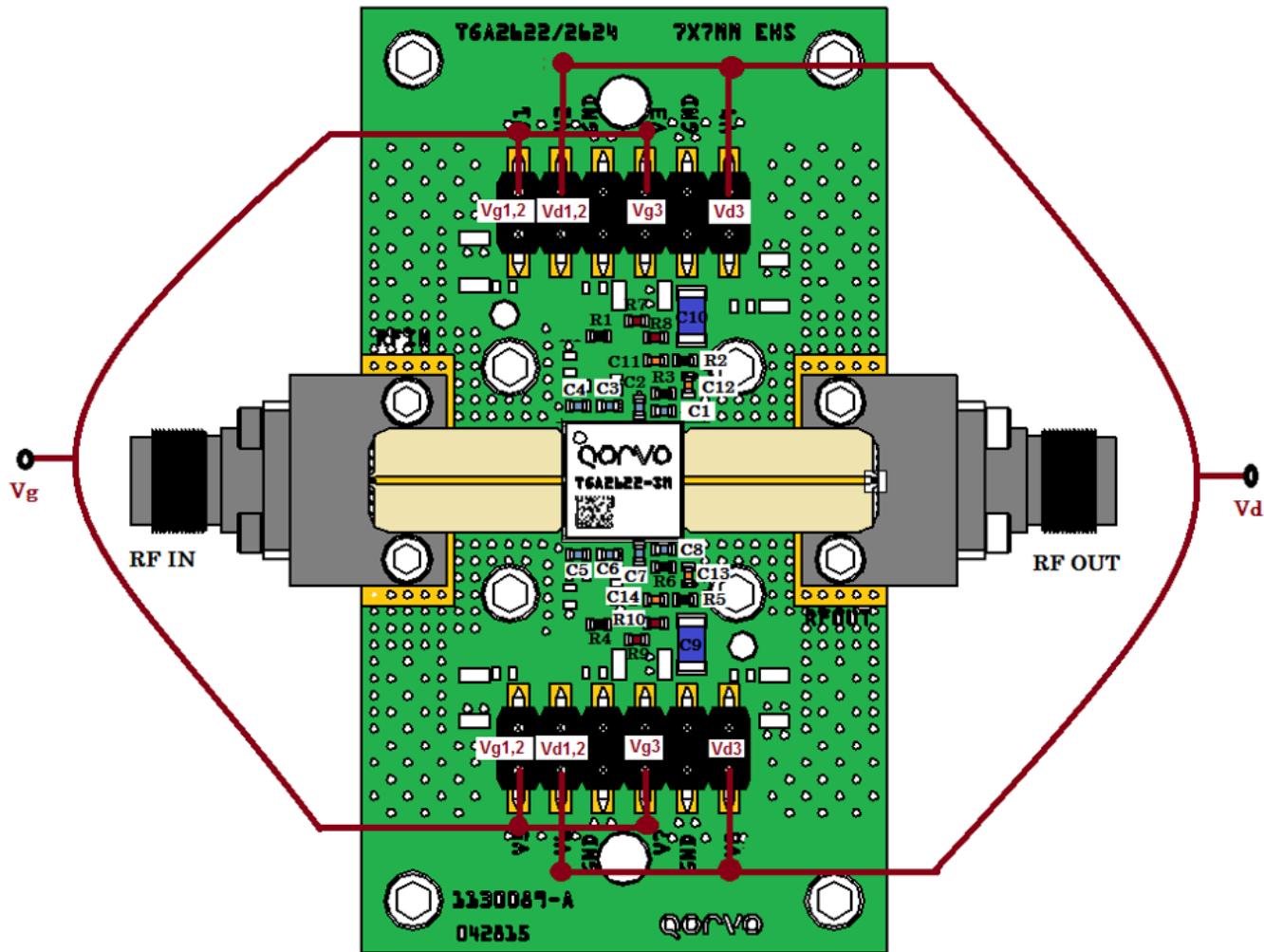


Recommended Land Pattern Mask

Units: Millimeters (mm)

Tolerances: unless specified: x.xx = ± 0.25 ; x.xxx = ± 0.100

Evaluation Board Layout



Notes: Both Top and Bottom VD and VG must be biased.

Bill of Materials

| Reference Des. | Value | Description | Manuf. | Part Number |
|----------------|--------------|---|---------|-------------|
| C1 – C8 | 1000 pF | Cap, 0402, 100 V, 10%, X7R | Various | |
| C9 – C10 | 10 μ F | Cap, 1206, 50 V, 20%, X5R | Various | |
| C11 – C14 | 0.01 μ F | Cap, 0402, 50 V, 10%, X7R | Various | |
| R1 – R6 | 10 ohms | Res, 0402, 50 V, 5%, SMD | Various | |
| R7 – R10 | 0 ohms | Res, 0402, jumpers required for the above EVB | Various | |

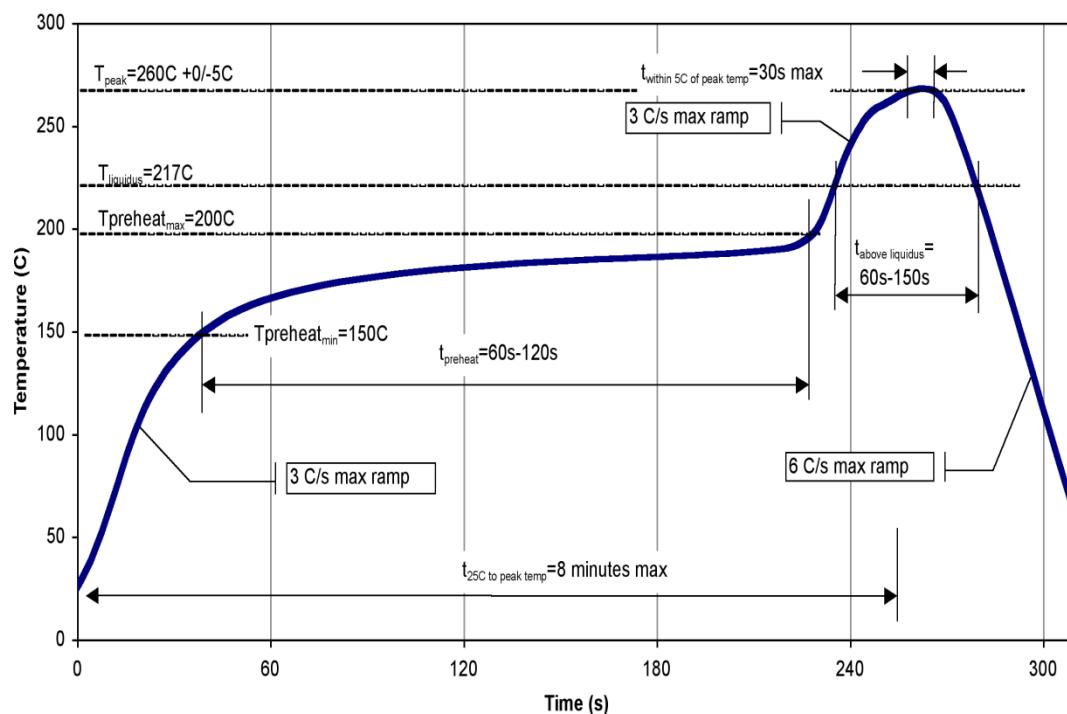
Assembly Notes

Compatible with lead-free soldering processes with 260°C peak reflow temperature.

This package is air-cavity and non-hermetic, and therefore cannot be subjected to aqueous washing. The use of no-clean solder to avoid washing after soldering is highly recommended.

Contact plating: Ni-Au.

Solder rework not recommended.



Recommended Soldering Temperature Profile

Handling Precautions

| Parameter | Rating | Standard |
|----------------------------------|----------|-----------------------|
| ESD – Human Body Model (HBM) | Class 1B | ANSI/ESD/JEDEC JS-001 |
| MSL – Moisture Sensitivity Level | Level 3 | IPC/JEDEC J-STD-020 |



Caution!
ESD-Sensitive Device

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A ($C_{15}H_{12}Br_4O_2$) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Tel: **1-844-890-8163**

Web: www.qorvo.com

Email: info-sales@qorvo.com

For technical questions and application information: **Email:** info-products@qorvo.com

Important Notices

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